

PATENT NUMBER

55	O.I.P.E.	PATENT DATE
SCANNED	Q.A.	

APPLICANTS

Il Kim

Method for forming silicon quantum dots and method for fabricating nonvolatile memory device using the same

PTO-204
12/89

ISSUING CLASSIFICATION												
ORIGINAL				CROSS REFERENCE(S)								
CLASS		SUBCLASS		CLASS	SUBCLASS (ONE SUBCLASS PER BLOCK)							
INTERNATIONAL CLASSIFICATION												

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	Sheets Drwg.	Figs. Drwg.	Print Fig.	Total Claims
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